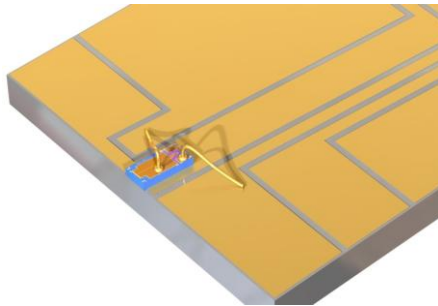


# COMB1310-50-CoC Preliminary

## 50GHz Comb-Laser, Chip on Submount


**Features:**

- 50 GHz channel spacing
- more than 19 channels at recommended operation point
- more than 30 channels possible for high bias voltage
- frequency modulated mode locking (no pulses)
- low relative intensity noise (RIN) of individual modes

**Applications:**

- O-band WDM signal source

### Recommended Operating Conditions

at CW; carrier is mounted on a heatsink

Parameter	Min.	Typ.	Max.	Unit
Chip Temperature	20	25	30	°C
LD Forward Current		300	400	mA
Reverse Bias Voltage	0	3	5	V

### Characteristics

only guaranteed under recommended (Typ.) operating conditions: CW, 25°C, 300mA, 3V

Parameter	Min.	Typ.	Max.	Unit
Total Optical Power	90	120		mW
Forward Voltage		2.1	2.5	V
Threshold Current		30	40	mA
Mean Wavelength*	1305	1310	1315	nm
Bandwidth (FWHM)	5.5	6		nm
Bandwidth (at -10 dB level)	9	9.3		nm
Mode Spacing	49	50	51	GHz
Average Optical Power per Channel**	4	5		mW
Number of Channels**	21	22		
Beating Spectrum Linewidth***		200	400	kHz
Individual mode RIN (averaged in DC-10GHz range)		-130	-125	dB/Hz
Polarization Extinction Ratio (PER)	18	20		dB
Slow Axis Beam Divergence (FWHM)	10	12	14	deg
Fast Axis Beam Divergence (FWHM)	37	38	39	deg

\*can be customized; \*\* at -3dB level; \*\*\*at -20dB level

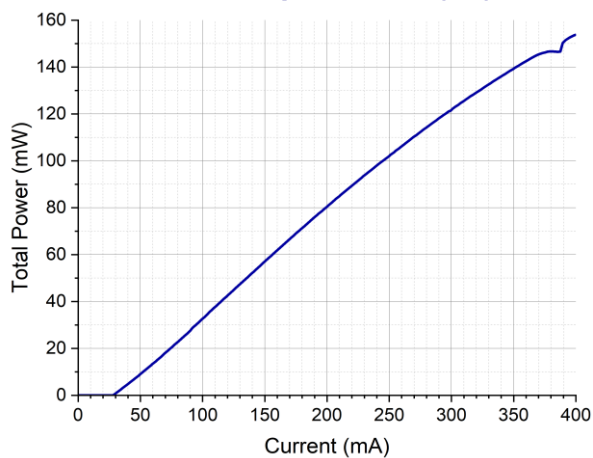
### Absolute Maximum Ratings

Parameter	Min	Max	Unit
LD Forward Current		400	mA
LD Reverse Voltage		1	V
Reverse Bias Voltage		5	V
Bias Forward Current		25	mA
Chip Operating Temperature	15	55	°C
Soldering Temperature (5 sec. max)		250	°C
Storage Temperature	-40	85	°C

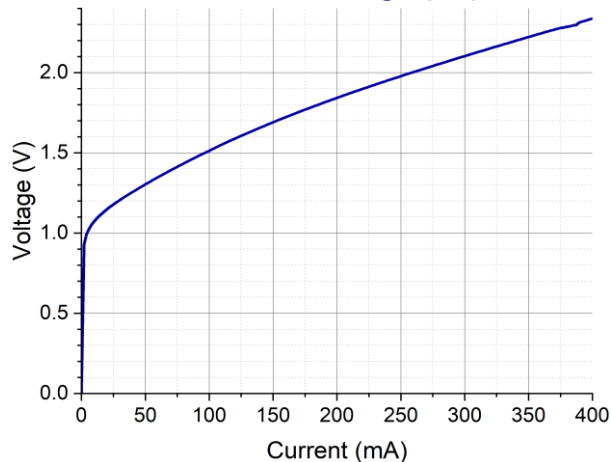
### Typical Performance

unless otherwise stated, measured at CW, 25°C, 300mA, 3V

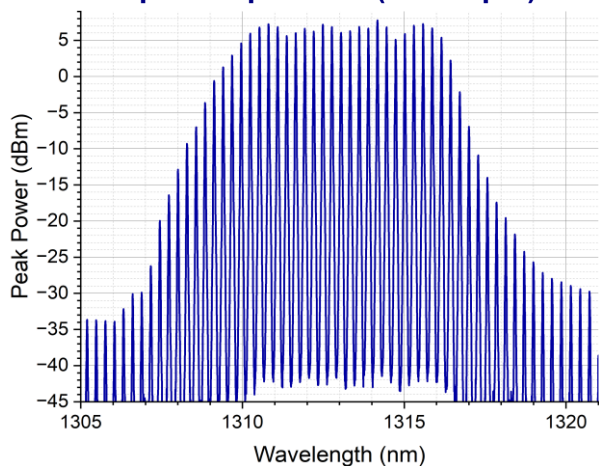
#### Total Output Power (L-I)



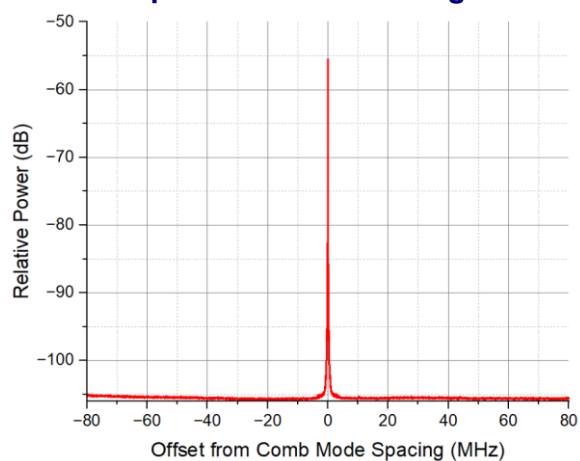
#### Forward Voltage (I-V)



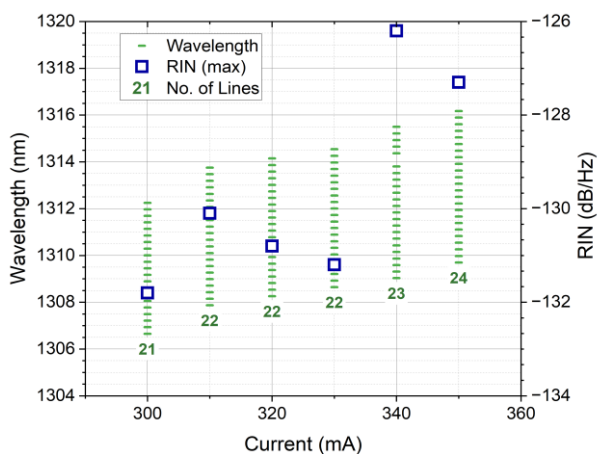
#### Optical Spectrum (res. 10pm)



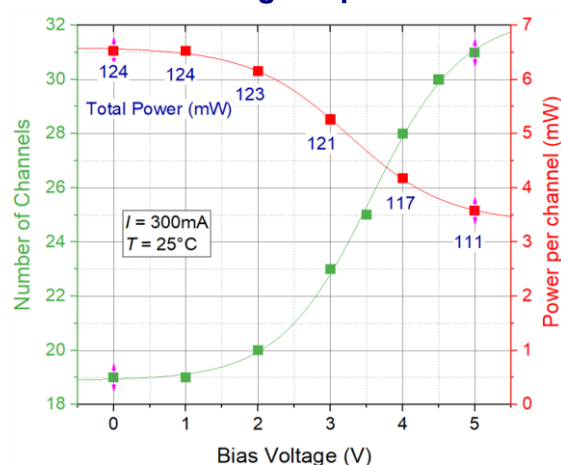
#### RF spectrum of all beating modes



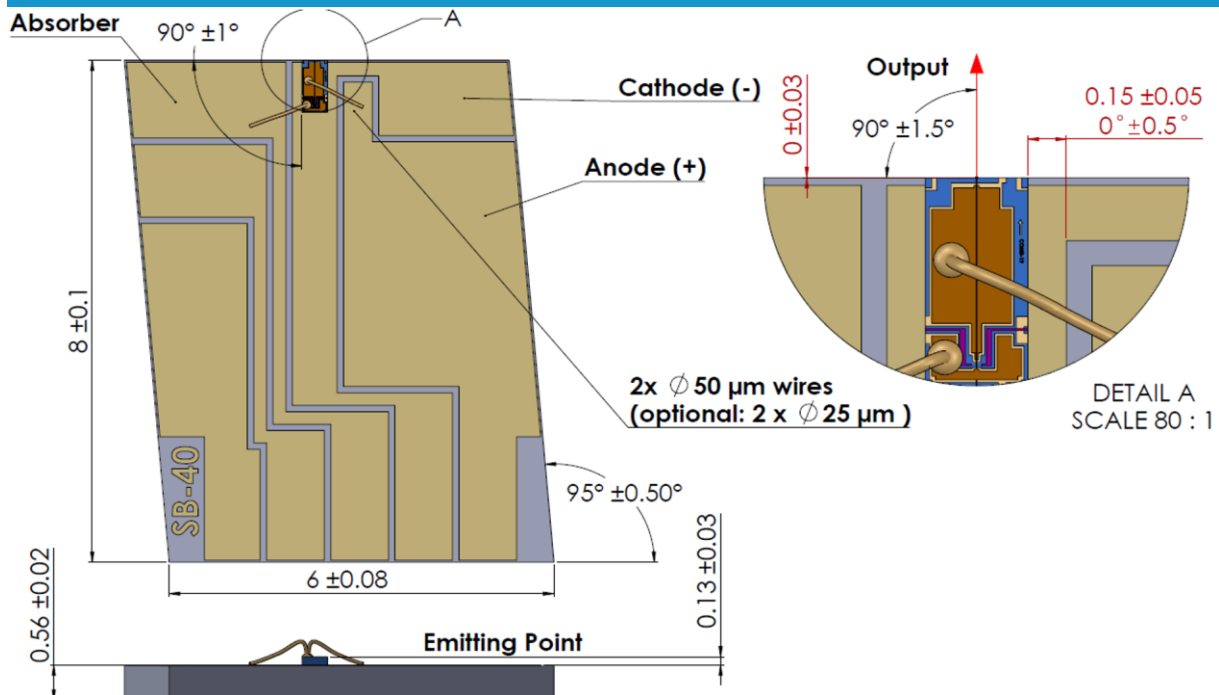
#### Individual Mode RIN



#### Bias Voltage Dependencies



**Dimensions (in mm), carrier can be customized**



## Safety and Operating Instructions

The light emitted from this device is invisible and can be harmful to the human eye. Avoid looking directly into the laser diode when the device is in operation. Proper laser safety eyewear must be worn during operation with open connector. Absolute Maximum Ratings may be applied to the device for short period of time only. Exposure to maximum ratings for extended period of time or exposure to more than one maximum rating may cause damage or affect the reliability of the device. Operating the device outside of its maximum ratings may cause device failure or a safety hazard. Power supplies used with the component must be employed such that the maximum forward current cannot be exceeded.

A proper heatsink for the device on thermal radiator is required. Sufficient heat dissipation and thermal conductance to the heatsink must be ensured either by flux-free soldering or by using of a thermal conductive and soft material (indium foil, graphite sheet) between the submount and the heatsink for thermal interface. It's undesirable to use thermal grease for this. Avoid back reflection to the device. It may give impact on the device performance in aspects of spectrum and power stability. It also may cause fatal facet damage. Using of optical isolators is highly recommended to block back reflection.

The Device is an Open-Heatsink Diode Laser; it may be operated in cleanroom atmosphere or dust-protected housing only. Operating temperature and relative humidity must be controlled to avoid water condensation on the laser facets. Any contamination or contact of the laser facet must be avoided

Electrostatic discharge is the primary cause of unexpected product failure. Take extreme precaution to prevent ESD. During device installation, ESD protection has to be maintained - use wrist straps, grounded work surfaces and rigorous antistatic techniques when handling the product.



**NOTE: Innolume product specifications are subject to change without notice**